

## Silicon Diffused Power Transistor

BU1507AX

## GENERAL DESCRIPTION

Enhanced performance, new generation, high-voltage, high-speed switching npn transistor in a plastic full-pack envelope intended for use in horizontal deflection circuits of colour television receivers and computer monitors. Features exceptional tolerance to base drive and collector current load variations resulting in a very low worst case dissipation.

## QUICK REFERENCE DATA

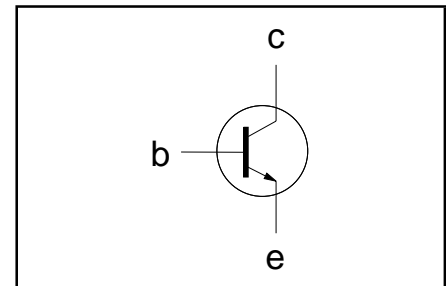
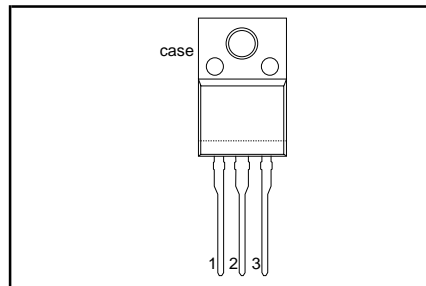
SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
$V_{CESM}$	Collector-emitter voltage peak value	$V_{BE} = 0\text{ V}$	-	1500	V
$V_{CEO}$	Collector-emitter voltage (open base)		-	700	V
$I_C$	Collector current (DC)		-	8	A
$I_{CM}$	Collector current peak value		-	15	A
$P_{tot}$	Total power dissipation	$T_{hs} \leq 25\text{ }^\circ\text{C}$	-	45	W
$V_{CESat}$	Collector-emitter saturation voltage	$I_C = 4\text{ A}; I_B = 0.95\text{ A}$	-	1.0	V
$V_{CEsat}$	Collector-emitter saturation voltage	$I_C = 4\text{ A}; I_B = 0.8\text{ A}$	-	5.0	V
$I_{Csat}$	Collector saturation current	$f = 16\text{ kHz}$	4	-	A
$t_f$	Fall time	$I_{Csat} = 4\text{ A}; f = 16\text{ kHz}$	0.25	0.5	$\mu\text{s}$

## PINNING - SOT186A

## PIN CONFIGURATION

## SYMBOL

PIN	DESCRIPTION
1	base
2	collector
3	emitter
case	isolated



## LIMITING VALUES

Limiting values in accordance with the Absolute Maximum Rating System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CESM}$	Collector-emitter voltage peak value	$V_{BE} = 0\text{ V}$	-	1500	V
$V_{CEO}$	Collector-emitter voltage (open base)		-	700	V
$I_C$	Collector current (DC)		-	8	A
$I_{CM}$	Collector current peak value		-	15	A
$I_B$	Base current (DC)		-	4	A
$I_{BM}$	Base current peak value		-	6	A
$-I_{B(AV)}$	Reverse base current	average over any 20 ms period	-	100	mA
$-I_{BM}$	Reverse base current peak value <sup>1</sup>		-	5	A
$P_{tot}$	Total power dissipation	$T_{hs} \leq 25\text{ }^\circ\text{C}$	-	45	W
$T_{stg}$	Storage temperature		-65	150	$^\circ\text{C}$
$T_j$	Junction temperature		-	150	$^\circ\text{C}$

## THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
$R_{th\ j-hs}$	Junction to heatsink	with heatsink compound	-	3.7	K/W
$R_{th\ j-a}$	Junction to ambient	in free air	55	-	K/W

<sup>1</sup> Turn-off current.

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BU1507AX

**ISOLATION LIMITING VALUE & CHARACTERISTIC** $T_{hs} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{isol}$	R.M.S. isolation voltage from all three terminals to external heatsink	$f = 50\text{-}60\text{ Hz}$ ; sinusoidal waveform; R.H. $\leq 65\%$ ; clean and dustfree	-		2500	V
$C_{isol}$	Capacitance from T2 to external heatsink	$f = 1\text{ MHz}$	-	10	-	pF

**STATIC CHARACTERISTICS** $T_{hs} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{CES}$	Collector cut-off current <sup>2</sup>	$V_{BE} = 0\text{ V}$ ; $V_{CE} = V_{CESMmax}$	-	-	1.0	mA
$I_{CES}$		$V_{BE} = 0\text{ V}$ ; $V_{CE} = V_{CESMmax}$ $T_j = 125\text{ }^{\circ}\text{C}$	-	-	2.0	mA
$I_{EBO}$	Emitter cut-off current	$V_{EB} = 7.5\text{ V}$ ; $I_C = 0\text{ A}$	-	-	1.0	mA
$BV_{EBO}$	Emitter-base breakdown voltage	$I_B = 1\text{ mA}$	7.5	13.5	-	V
$V_{CEOsust}$	Collector-emitter sustaining voltage	$I_B = 0\text{ A}$ ; $I_C = 100\text{ mA}$ ; $L = 25\text{ mH}$	700	-	-	V
$V_{CEsat}$	Collector-emitter saturation voltages	$I_C = 4\text{ A}$ ; $I_B = 0.8\text{ A}$	-	-	5.0	V
$V_{BEsat}$	Base-emitter saturation voltage	$I_C = 4\text{ A}$ ; $I_B = 0.8\text{ A}$	-	-	1.1	V
$h_{FE}$	DC current gain	$I_C = 100\text{ mA}$ ; $V_{CE} = 5\text{ V}$	-	17	-	
$h_{FE}$		$I_C = 4\text{ A}$ ; $V_{CE} = 5\text{ V}$	5.0	7.0	9.0	

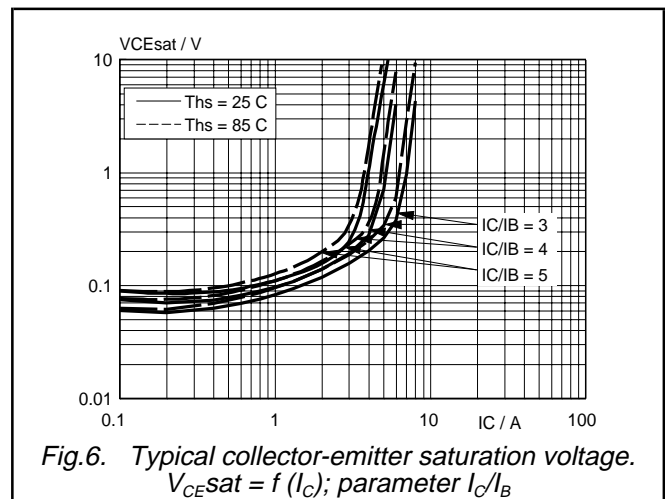
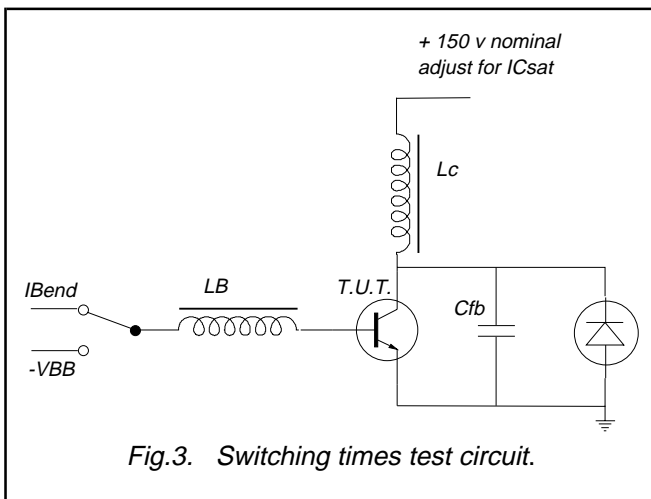
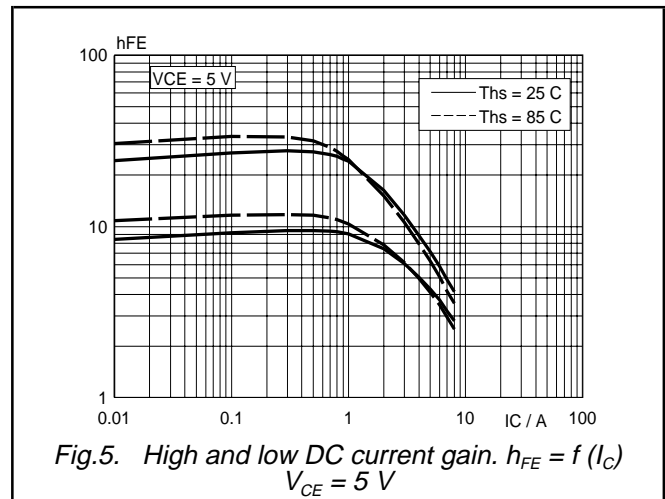
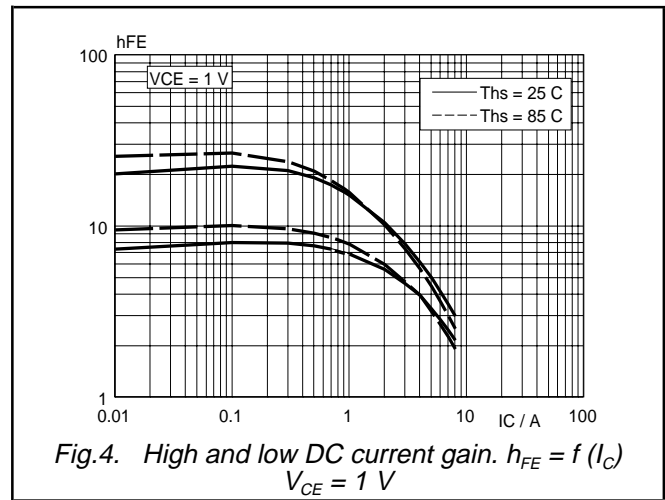
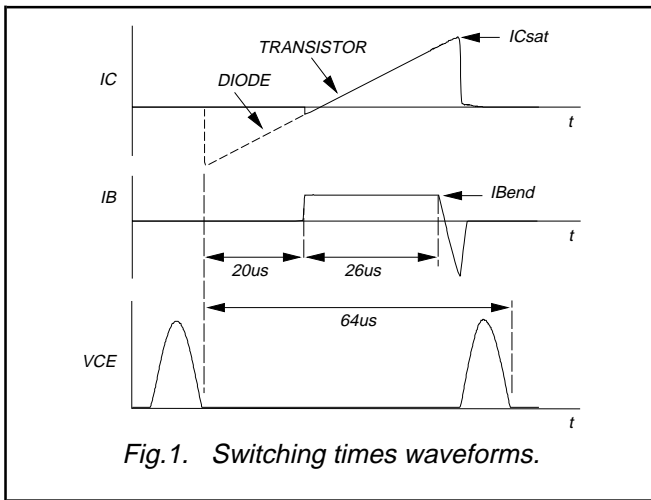
**DYNAMIC CHARACTERISTICS** $T_{hs} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
$C_c$	Collector capacitance	$I_E = 0\text{ A}$ ; $V_{CB} = 10\text{ V}$ ; $f = 1\text{ MHz}$	68	-	pF
$t_s$	Switching times (16 kHz line deflection circuit)	$I_{Csat} = 4\text{ A}$ ; $I_{B(end)} = 0.7\text{ A}$ ; $L_B = 6\text{ }\mu\text{H}$ ; $-V_{BB} = 4\text{ V}$			
$t_s$	Turn-off storage time		5.0	6.0	$\mu\text{s}$
$t_f$	Turn-off fall time		0.25	0.5	$\mu\text{s}$

<sup>2</sup> Measured with half sine-wave voltage (curve tracer).

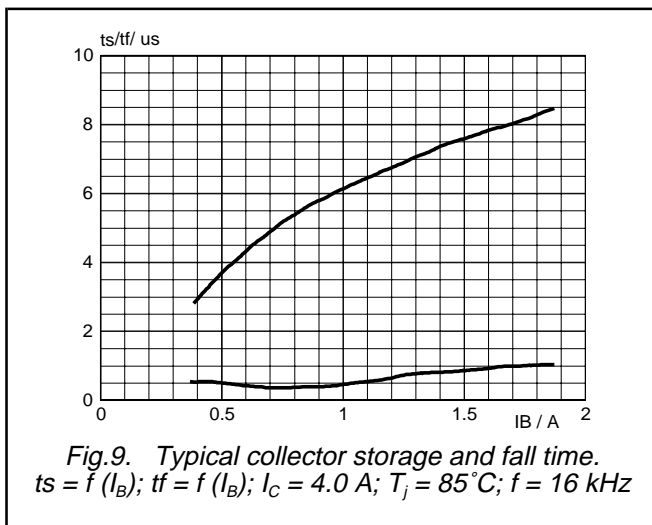
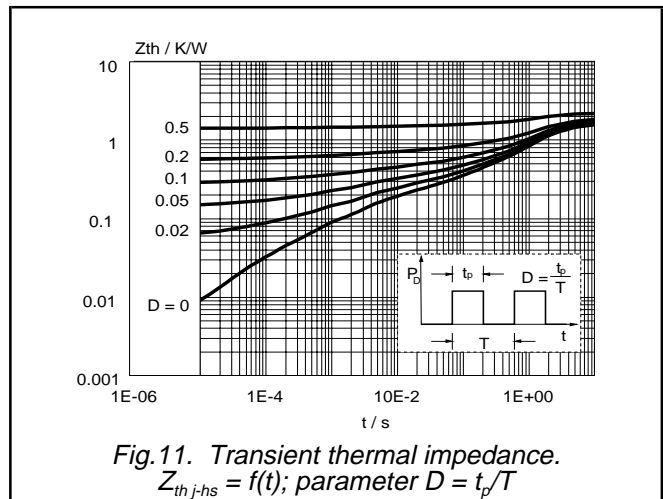
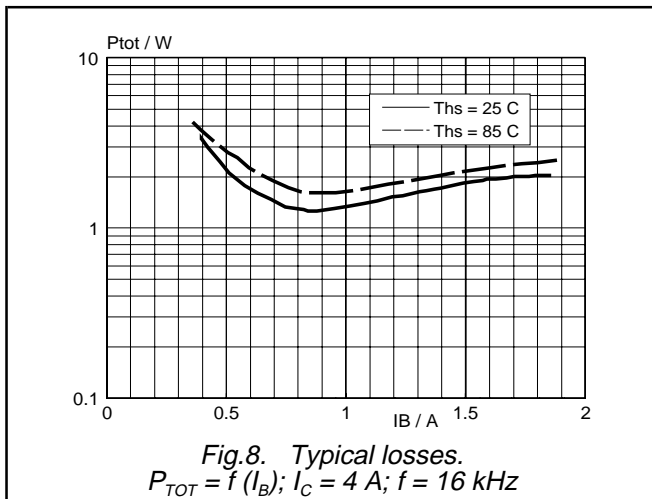
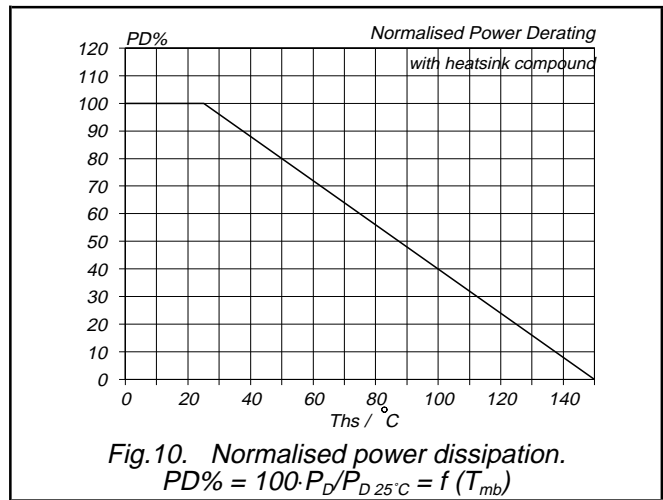
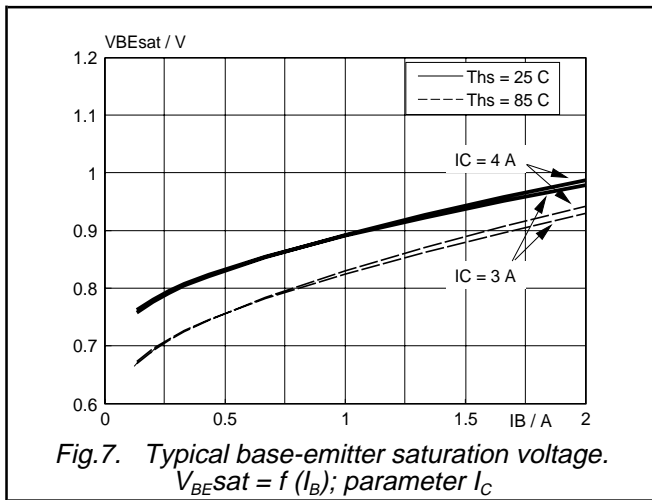
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**MECHANICAL DATA**

*Dimensions in mm*

*Net Mass: 2 g*



Fig.12. SOT186A; The seating plane is electrically isolated from all terminals.

**Notes**

1. Refer to mounting instructions for F-pack envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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**DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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